



#### **Product Summary**

BV <sub>DSS</sub>	Rds(ON) Max	ID TA = +25°C
	2Ω @V <sub>GS</sub> = 5V	480mA
50V	2.5Ω @V <sub>GS</sub> = 2.5V	440mA
	4Ω @V <sub>GS</sub> = 1.8V	370mA

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Battery management systems
- Power management functions
- Load switches

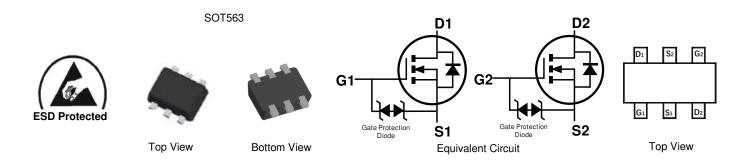
# Features and Benefits

- Dual N-Channel MOSFET
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

**50V N-CHANNEL ENHANCEMENT MODE MOSFET** 

#### **Mechanical Data**

- Package: SOT563
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)



### Ordering Information (Note 4)

Part Number	Baakaga	Packing		
	Package	Qty.	Carrier	
DMN52D0UVA-7	SOT563	3,000	Reel	
DMN52D0UVA-13	SOT563	10,000	Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

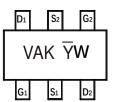
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**



#### Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	2	3	4	5	6	7	8	9	0	1	2	3
Week	1-26				1-26 27-52					5	53	
Code		A-Z				a	l-Z				Z	

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		VDSS	50	V	
Gate-Source Voltage	Vgss	±12	V		
Continuous Drain Current (Note 6) VGS = 5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	480 380	mA
Maximum Continuous Body Diode Forward Curr	rent (Note 6)		ls	480	mA
Pulsed Drain Current (10µs Pulse, Duty Cycle =	: 1%)	Ідм	1.2	A	
Pulsed Source Current (10µs Pulse, Duty Cycle	= 1%)	Ism	1.2	A	

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.48	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	261	°C/W
Total Power Dissipation (Note 6)		PD	0.89	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	139	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes:5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1 inch square copper plate.



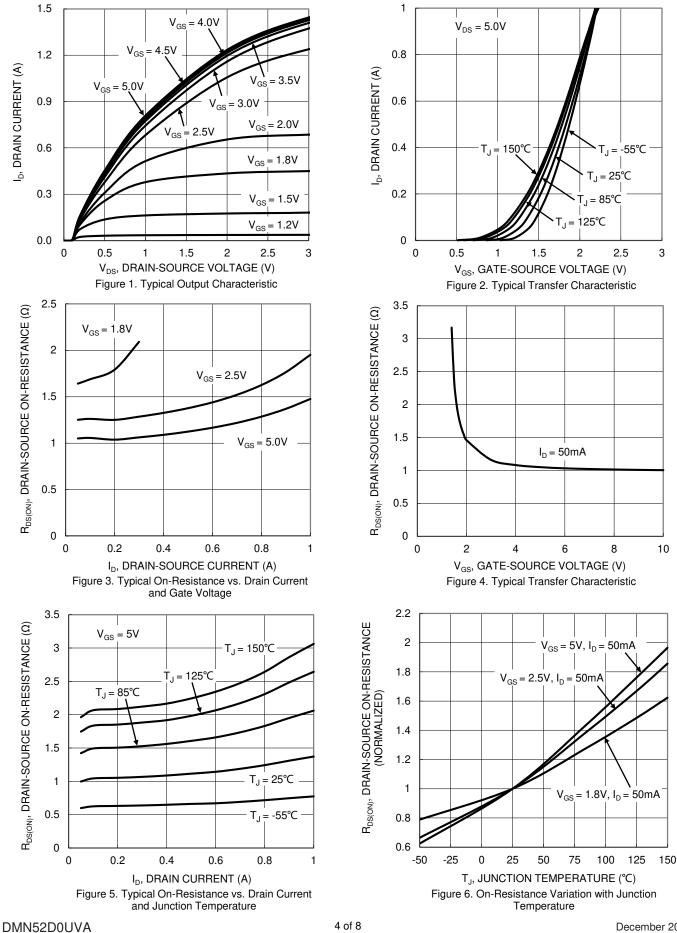
## Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

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	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			1	1		
Drain-Source Breakdown Voltage	BVDSS	50	—	—	V	Vgs = 0V, Id = 250µA
Zero Gate Voltage Drain Current	IDSS	_	—	1	μΑ	$V_{DS} = 50V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	—	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.49	—	1.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
			1.6	4.0		$V_{GS}=1.8V,\ I_{D}=50mA$
Static Drain-Source On-Resistance	RDS(ON)		1.2	2.5	Ω	$V_{GS} = 2.5V, I_D = 50mA$
		-	1.0	2.0		$V_{GS} = 5.0V, I_{D} = 50mA$
Diode Forward Voltage	Vsd	_	0.6	1.2	V	$V_{GS} = 0V, I_D = 50mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		39	—	pF	
Output Capacitance	Coss		4.8	_	pF	− V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, − f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	3.6	—	pF	
Gate Resistance	Rg	_	47.8	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	0.8	—	nC	
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	1.5	—	nC	V <sub>DS</sub> = 25V, I <sub>D</sub> = 50mA
Gate-Source Charge	Q <sub>gs</sub>		0.1	_	nC	$V_{\rm DS} = 25V, ID = 5011A$
Gate-Drain Charge	Q <sub>gd</sub>	_	0.1	—	nC	
Turn-On Delay Time	td(on)		1.05	-	ns	
Turn-On Rise Time	tR	_	11.3	—	ns	$V_{DS} = 25V, V_{GS} = 10V,$
Turn-Off Delay Time	td(OFF)	—	33	—	ns	$R_G = 50\Omega$ , $I_D = 50mA$
Turn-Off Fall Time	tF	—	38.5	—	ns	

Notes:7. Short duration pulse test used to minimize self-heating effect.8. Guaranteed by design. Not subject to product testing.



### DMN52D0UVA



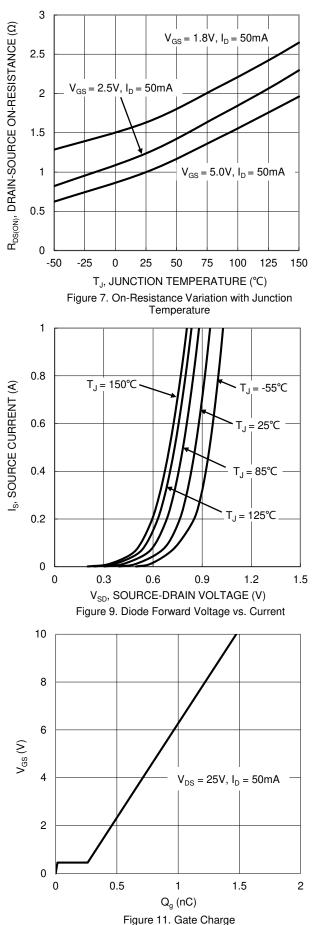
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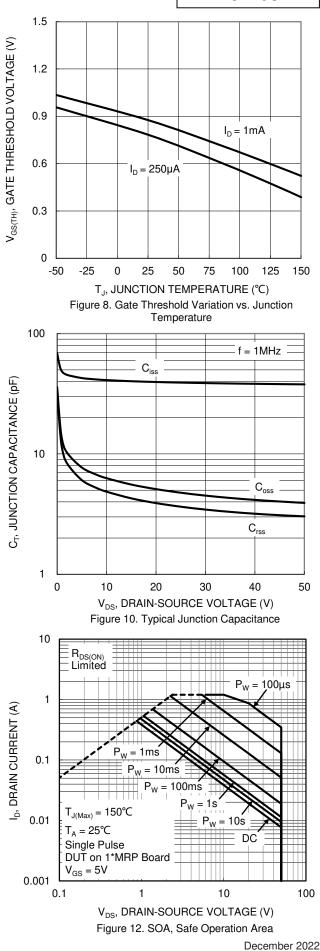
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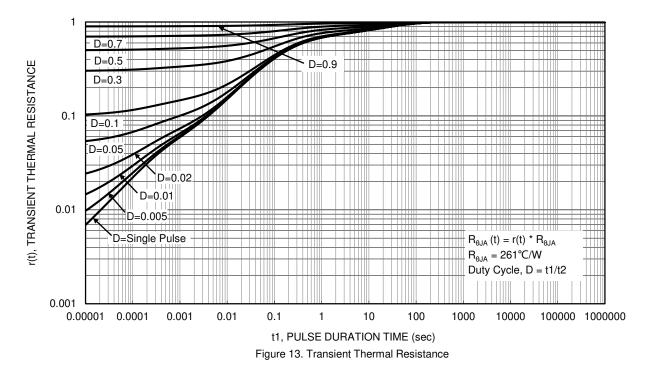




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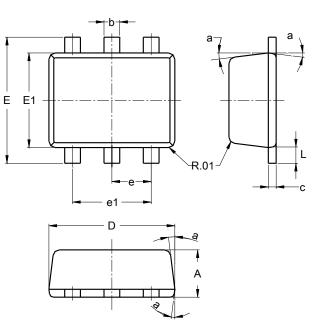






#### **Package Outline Dimensions**

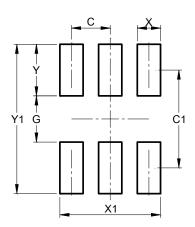
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563							
Dim	Min	Max	Тур				
Α	0.55	0.60					
b	0.15	0.30	0.20				
С	0.10	0.18	0.11				
D	1.50	1.70	1.60				
Е	1.55	1.70	1.60				
E1	1.10	1.25	1.20				
е			0.50				
e1	0.90	1.10	1.00				
L	0.10	0.30	0.20				
а	8°	9°	7°				
All	All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563

Dimensions	Value (in mm)			
С	0.500			
C1	1.270			
G	0.600			
Х	0.300			
X1	1.300			
Y	0.670			
Y1	1.940			

SOT563



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